**ON Semiconductor** 

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# Onsemi

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# **Bipolar Power Transistors** 40 V, 3.0 A, Low V<sub>CE(sat)</sub> PNP Transistor

ON Semiconductor's  $e^2$ PowerEdge family of low  $V_{CE(sat)}$  transistors are surface mount devices featuring ultra low saturation voltage ( $V_{CE(sat)}$ ) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### Features

- Complement to NSS40301MZ4 Series
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

( <b>b</b>					
Rating	Symbol	Value	Unit		
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc		
Collector-Base Voltage	V <sub>CB</sub>	40	Vdc		
Emitter-Base Voltage	V <sub>EB</sub>	6.0	Vdc		
Base Current – Continuous	Ι <sub>Β</sub>	1.0	Adc		
Collector Current – Continuous	Ι <sub>C</sub>	3.0	Adc		
Collector Current – Peak	I <sub>CM</sub>	5.0	Adc		
Total Power Dissipation Total P <sub>D</sub> @ T <sub>A</sub> = 25°C (Note 1) Total P <sub>D</sub> @ T <sub>A</sub> = 25°C (Note 2)	P <sub>D</sub>	2.0 0.80	W		
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C		

MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Mounted on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material.

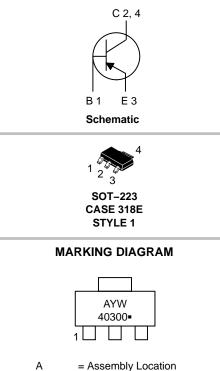
2. Mounted on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material.



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# PNP TRANSISTOR 3.0 AMPERES 40 VOLTS, 2.0 WATTS



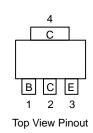


Y

W

- = Work Week
- 40300 = Specific Device Code
  - = Pb–Free Package

#### PIN ASSIGNMENT



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case Junction-to-Ambient on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material Junction-to-Ambient on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material	R <sub>θJA</sub> R <sub>θJA</sub>	64 155	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0 \text{ Adc}$ )	V <sub>CEO(sus)</sub>	40	-	-	Vdc
Emitter-Base Voltage ( $I_E = 50 \ \mu Adc$ , $I_C = 0 \ Adc$ )	V <sub>EBO</sub>	6.0	-	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 40 Vdc)	I <sub>CBO</sub>	-	-	100	nAdc
Emitter Cutoff Current (V <sub>BE</sub> = 6.0 Vdc)	I <sub>EBO</sub>	_	_	100	nAdc

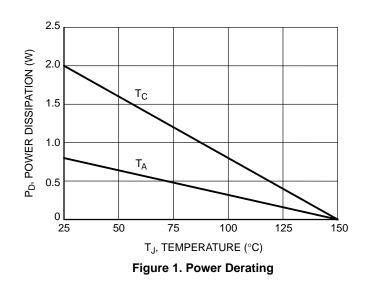
#### **ON CHARACTERISTICS** (Note 3)

	V <sub>CE(sat)</sub>	- - -	- - -	0.070 0.150 0.400	Vdc
Base–Emitter Saturation Voltage ( $I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$ )	V <sub>BE(sat)</sub>	-	-	1.0	Vdc
Base–Emitter On Voltage ( $I_C = 1.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$ )	V <sub>BE(on)</sub>	-	-	0.9	Vdc
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 0.5 \; \text{Adc},  V_{CE} = 1.0 \; \text{Vdc}) \\ (I_{C} = 1.0 \; \text{Adc},  V_{CE} = 1.0 \; \text{Vdc}) \\ (I_{C} = 3.0 \; \text{Adc},  V_{CE} = 1.0 \; \text{Vdc}) \end{array} $	h <sub>FE</sub>	200 175 100		_ 350 _	-

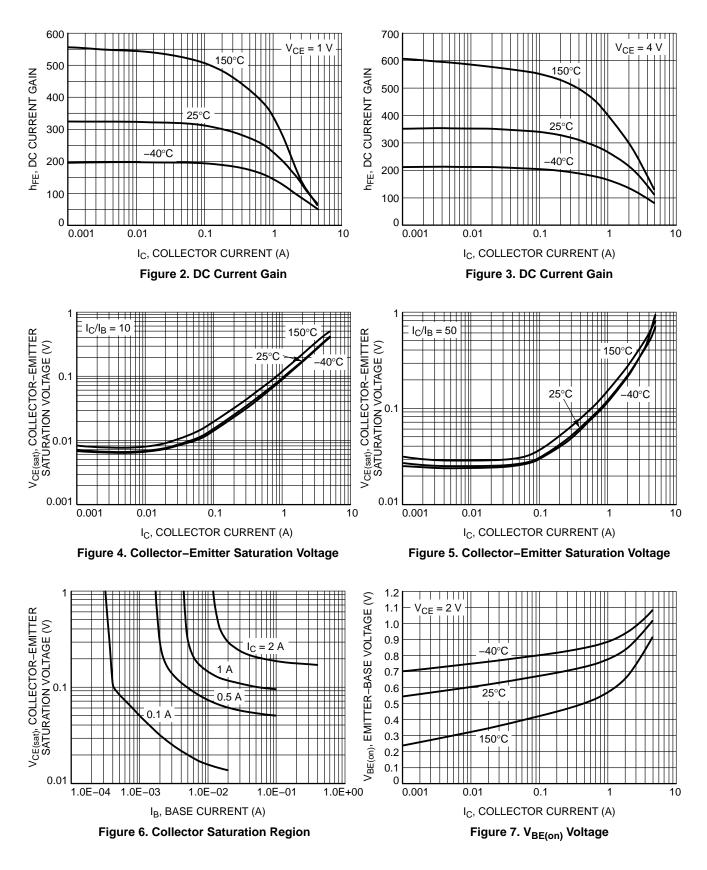
#### DYNAMIC CHARACTERISTICS

Output Capacitance (V <sub>CB</sub> = 10 Vdc, f = 1.0 MHz)	C <sub>ob</sub>	-	40	-	pF
Input Capacitance (V <sub>EB</sub> = 5.0 Vdc, f = 1.0 MHz)	C <sub>ib</sub>	-	130	-	pF
Current–Gain – Bandwidth Product (Note 4) $(I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}, F_{test} = 1.0 \text{ MHz})$	f <sub>T</sub>	_	160	-	MHz

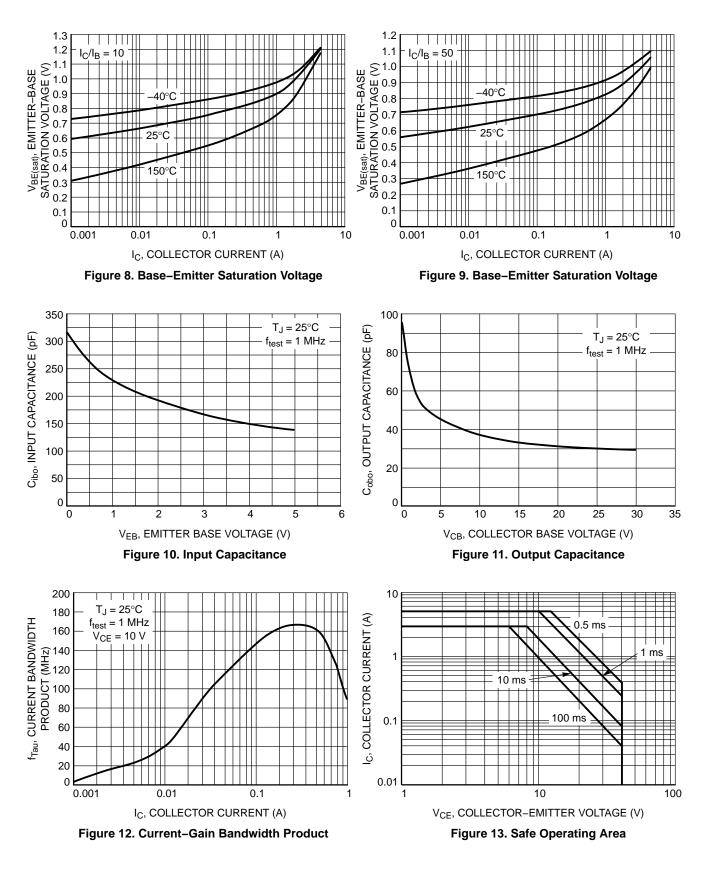
3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%. 4. f<sub>T</sub> = |h<sub>FE</sub>| • f<sub>test</sub>



## **TYPICAL CHARACTERISTICS**



## **TYPICAL CHARACTERISTICS**



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS40300MZ4T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSV40300MZ4T1G*	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSS40300MZ4T3G	SOT-223 (Pb-Free)	4,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

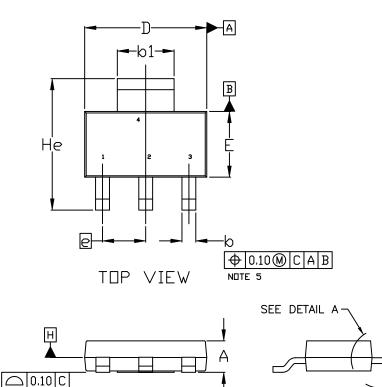
Capable

DATE 02 OCT 2018





SCALE 1:1



С

-11

SIDE VIEW

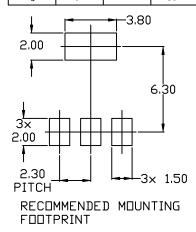
DETAIL A

A1

SOT-223 (TO-261) CASE 318E-04 ISSUE R

- NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- 5. AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61.

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
A	1.50	1.63	1.75		
A1	0.02	0.06	0.10		
b	0.60	0.75	0.89		
b1	2.90	3.06	3.20		
с	0.24	0.29	0.35		
D	6.30	6.50	6.70		
E	3.30	3.50	3.70		
e		2.30 BSC			
L	0.20				
L1	1.50	1.75	2.00		
He	6.70	7.00	7.30		
θ	0*		10*		



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FRONT VIEW

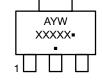
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#### SOT-223 (TO-261) CASE 318E-04 ISSUE R

#### DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: PIN 1. INPUT 2. GROUND 3. LOGIC 4. GROUND	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	Style 12: Pin 1. Input 2. Output 3. NC 4. Output	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

# GENERIC MARKING DIAGRAM\*



- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package
- (Note: Microdot may be in either location) \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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